## NSN 5961-01-158-2504

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-158-2504 **Inclosure Material:** Metal **Overall Length:** 1.575 inches **Overall Height:** 0.326 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact-darlington connected **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 8.00 amperes service voltage and 20.12 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Precious Material And Location:** Leads gold **Precious Material:** Gold **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a

No

**Unit Of Measure:** 

Demilitarization:

## **NSN 5961-01-158-2504** Transistor - Page 2 of 2



Fiig:

A110a0